Two-eigenfunction correlation in a multifractal metal and insulator

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We consider the correlation of two single-particle probability densities $|\Psi_E(\mathbf{r})|^2$ at coinciding points \mathbf{r} as a function of the energy separation $\omega = |E - E'|$ for disordered tight-binding lattice models (the Anderson models) and certain random matrix ensembles. We focus on the parameter range close but not exactly at the Anderson localization transition. We show that even away from the critical point the eigenfunction statistics exhibit the remnant of multifractality characteristic of the critical states. This leads to an enhancement of eigenfunction correlations and a corresponding enhancement of matrix elements of the local electron interaction at small energy separations. This enhancement is accompanied by a depression of correlations at large energy separations, both phenomena being a consequence of the stratification of space into densely packed but mutually avoiding resonance clusters. We also demonstrate that the correlation function of localized states in a *d*-dimensional insulator is logarithmically enhanced at small energy separations provided that d > 1. A simple and general physical picture of all these phenomena is presented.

Finally by a combination of numerical results on the Anderson model and analytical and numerical results for the relevant random matrix theories we identified the Gaussian random matrix ensembles that describe the multifractal features both in the metal and in the insulator phases.

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I. INTRODUCTION

Eigenfunction and spectral statistics in quantum systems with quenched disorder were a subject of intense study¹ in the context of mesoscopic fluctuations of conductance and density of states (DoS), in particular in quantum $dots^2$. For this application the most relevant is the regime of weak deviation^{3,4} from the Wigner-Dyson statistics given by the conventional random matrix theory $(RMT)^5$. Disordered multi-channel quantum wires is the most important example of systems where singleparticle eigenstates are all localized. Here the statistics of eigenstates require a non-perturbative treatment using the formalism of nonlinear sigma-model⁶ or banded random matrices⁷. A special class are systems with the critical, multifractal (MF) eigenstate statistics^{1,8,9}. Twodimensional disordered metals fall in this class¹⁰ provided that effects of localization are suppressed by magnetic field. Otherwise, one can speak only on weak multifractality which turns to localization before being fully developed. The true physical realizations of the critical, MF eigenstate statistics are systems at the critical point of the Anderson localization transition 11,12 and the integer Quantum Hall systems at the center of Landau band¹³. Importantly, the class of systems with MF eigenstate statistics also allows for a random matrix representation⁸, in particular using the power-law banded random matrices $(PLBRM)^{14}$.

Another field of intense research is the interplay between disorder and electron interaction with the seminal results on quantum correction to the tunnel DoS and conductivity¹⁵ of disordered two-dimensional metals and the correction to superconducting transition temperature due to a simultaneous effect of disorder and the Coulomb interaction¹⁶. In all those works disorder and interaction are taken into account essentially perturbatively along the lines given in¹⁷. Recently there was an attempt¹⁸ to consider the problem of superconductivity near the Anderson transition in which disorder has been treated nonperturbatively by *postulating* the MF statistics of oneparticle states $\Psi_i(\mathbf{r})$ that enter the matrix element of a phenomenological electron attraction:

$$J_{ij} = g \int \mathbf{dr} \, \Psi_i(\mathbf{r})^2 \, \Psi_j(\mathbf{r})^2. \tag{1}$$

In particular, the simplest quantity of interest is the disorder average matrix element $\langle J_{ij} \rangle$ at a given energy separation ω between one-particle energies E_i and E_j . For real eigenfunctions (orthogonal symmetry class) it is proportional to the correlation function $C(\omega) = K(\omega)/R(\omega)$, where

$$K(\omega) = \int \mathbf{dr} \, \sum_{i,j} \langle |\Psi_i(\mathbf{r})|^2 \, |\Psi_j(\mathbf{r})|^2 \, \delta(E_i - E_j - \omega) \rangle, \ (2)$$

and $R(\omega) = \sum_{ij} \langle \delta(E_i - E_j - \omega) \rangle$ is the spectral correlation function which is close to 1 for ω much greater then the mean level spacing. The correlation function $C(\omega) \approx K(\omega)$ is the main subject of the present paper.

The correlation function defined by Eq.(2) is a measure of overlap of *two different* eigenfunctions. For truly extended normalized states (e.g. in a quantum dot) $|\Psi_i(\mathbf{r})|^2 = 1/\mathcal{V}$ and thus $C(\omega)\mathcal{V} = 1$, where \mathcal{V} is a system volume. Remarkably, $C(\omega)\mathcal{V} = 1$ is also valid for

classical examples of localized states, e.g. in a quantum disordered wire. In this case two states are typically not overlapping but with a small probability of ξ^d / \mathcal{V} (where ξ is the localization radius) they are localized in the same place and then the integral in Eq.(2) is of the order of the inverse localization volume $1/\xi^d$.

There are cases, however, when an eigenfunction $\Psi_i(\mathbf{r})$ does not occupy all the available volume or all the localization volume and the typical amplitude $|\Psi_i(\mathbf{r})|^2$ is not just the inverse volume (for extended states) or the inverse localization volume (for localized states). In this case a non-trivial behavior of the correlation function $C(\omega)$ is expected. Such situation is realized near the critical point of the Anderson localization transition. In the vicinity of this point in the region of extended states (*multifractal metal*) or in the region of localized states (*multifractal insulator*) the system retains the characteristic features of the critical multifractal statistics of eigenstates which makes it qualitatively different from both a normal metal or a normal Anderson insulator.

In this paper we will identify and quantify such characteristic features in the correlation function $C(\omega)$ and give their interpretation in terms of the typical behavior of single-particle states. To attain this goal we will combine new analytical results for the PLBRM with numerics on the PLBRM and the Anderson model. We specially focus on the dependence of $C(\omega)$ on the energy difference ω in the cross-over region in the vicinity but not exactly at the Anderson transition point which has not been studied so far.

The paper is organized as follows. In section II we give a brief introduction into the subject of multifractality of critical eigenstates focusing on the main effect of multifractality which is the critical enhancement of eigenfunction correlations. In section III we give a cartoon of the off-critical states in a multifractal metal and a multifractal insulator and introduce the random matrix theories which may describe them. In Sec.IV we present the results of an analytical theory of eigenfunction correlations for a class of almost diagonal Gaussian random matrices which all the RMT's suggested to describe strong multifractality fall into. In Sec.V we consider the twoeigenfunction correlation function exactly at the critical point of the localization transition in the 3D Anderson model and for the critical random matrix ensemble in the limit of strong multifractality. We show that the dynamical scaling relationship suggested by Chalker is not violated even in the limit when the fractal dimensions are very small. In Section VI we describe the new phenomenon of eigenfunction mutual avoiding and present a qualitative picture that simultaneously explains the enhancement of eigenfunction correlations at small energy separations and the eigenfunction mutual avoiding at large energy separations. In section VII we consider the properties of eigenfunction correlations in a multifractal insulator. In particular, we describe the new phenomenon of logarithmic enhancement of eigenfunction correlations at small energy separations in the 2D and 3D Anderson insulators and show the absence of such enhancement in the quasi-1D case. We also suggest a Truncated Critical RM ensemble that describes all the principal features of eigenfunction correlations in the 3D multifractal insulator. Section VIII is devoted to the random matrix description of the multifractal metal. We show that the sub-critical PLBRM suggested in Ref.¹⁴ gives a reasonable agreement with the 3D Anderson model. By analytical treatment of this RM model we found the region of parameters where the eigenfunction correlations become effectively short-range in the energy space which may poit out on the existence of a new metal phase above some critical dimensionlity in the multi-dimensional Anderson model. In the Conclusion we list all the principal results of this paper.

II. MULTIFRACTALITY OF CRITICAL EIGENFUNCTIONS

The "standard" model (the Anderson model) for the And erson localization transition in d > 2 dimensions is the tight-binding model with the hopping constant V = 1and random on-site energies ε_i characterized by the distribution function $\mathcal{P}(\varepsilon_i)$ which is frequently chosen constant $\mathcal{P}(\varepsilon_i) = 1/W$ in the interval [-W/2, W/2] and zero otherwise. There is a vast literature (see e.g.¹⁹ and references therein) on numerical investigation of the Anderson localization transition in this model on a 3D lattice. Recently also higher dimensions d > 3 become accessible to modern computers 20 . While the earlier studies of this model were focused on the critical behavior of the localization/correlation length ξ near the critical disorder W_c , the recent works were mostly related with the statistics of critical eigenfunctions. The multifractality of critical eigenfunctions predicted in¹¹ almost immediately after emergence of scaling theory of localization has been confirmed and quantified in detail.

The results obtained for the Anderson model exactly at the critical point seem to be very well described²¹ by the critical PLBRM model^{8,14}. This model is defined as an ensemble of random Hermitean matrices which entries H_{ij} fluctuate independently around zero with the variance:

$$\langle |H_{ij}|^2 \rangle = \begin{cases} \beta^{-1}, & i = j\\ \frac{1}{2\left[1 + \frac{|i-j|^2}{b^2}\right]}, & i \neq j \end{cases},$$
(3)

where $\beta = 1, 2, 4$ for the Dyson orthogonal, unitary, and symlectic symmetry classes⁵ and b is the parameter that controls the multifractality exponents. This model has been studied and its comparison with the Anderson model in d dimensions has been done predominantly for the statistical moments P_n of a single eigenstate at a given energy E:

$$P_q(E) = \rho^{-1} \sum_n \sum_{\mathbf{r}} \langle |\Psi_n(\mathbf{r})|^{2q} \,\delta(E - E_n) \rangle. \tag{4}$$

The best known example is the inverse participation ratio (IPR) given by the second moment P_2 . The multifractal statistics of a single eigenstate is characterized by the moment P_q that scales with the system volume \mathcal{V} or the total number of sites N as:

$$P_q \propto N^{-(q-1)d_q/d},\tag{5}$$

where $d_q < d$ is the fractal dimension corresponding to q-th moment. The existence of the scaling law Eq.(5) and the dependence of the exponent d_q on q are the principle features of *eigenfunction multifractality*. The fractal exponents d_q depend also on the symmetry class β and the space dimensionality d. For the critical PLBRM Eq.(3) the dependence on d is modeled by the dependence of d_q on the parameter b.

The critical scaling Eq.(5) with respect to the system size N has its dynamical counterpart when instead of one single eigenfunction one considers the correlation function Eq.(2) of two eigenfunctions at an energy separation $\omega = |E - E'|$ between them. This scaling has been suggested by Chalker^{12,13} many years ago:

$$C(\omega) = \frac{1}{N} \left(\frac{E_0}{\omega}\right)^{\mu}, \quad \delta < \omega < E_0, \tag{6}$$

where

$$\mu = 1 - \frac{d_2}{d},\tag{7}$$

 δ is the mean level spacing and E_0 is the upper cutoff of multifractality. Numerics on the integer Quantum Hall systems and in the critical point of the 3D Anderson model was consistent^{22,23} with this scaling.

An important feature of Eq.(6) is that the exponent $1 - d_2/d$ in the ω -dependence is smaller than 1. Even in the limit of infinitely small correlation dimension d_2 the correlation function decays slowly as $1/\omega$. This implies that the sparse critical states separated by large energy distance are still well overlaping²⁴, in contrast to strongly localized states which typically do not overlap even for nearest neighbors in the energy space. The reason for such a behavior and the physical meaning of the energy scale E_0 will be discussed in Section VI.

As the correlation function is equal to $C(\omega) \approx 1/N$ both for the truly extended and the ideal localized states, Eq.(6) implies the *critical enhancement* of eigenfunction correlations for $\omega < E_0$. This enhancement is crucially important for electron interaction near the Anderson localization transition, in particular for the superconducting transition temperature¹⁸. To illustrate this point we present in Fig.1 the result of numerical diagonalization of the critical PLBRM, the classical Wigner-Dyson RM $\langle |H_{ij}|^2 \rangle = const$ with extended eigenstates, and the ensemble of conventional banded random matrices⁷ with exponentially decreasing entries $\langle |H_{ij}|^2 \rangle \propto \exp\left(-|i-j|/B\right)$ which describes strongly localized eigenstates in quasi-1D disordered systems. The critical enhancement of eigenfunction correlations is evident from this plot.



FIG. 1: Critical enhancement of eigenfunction correlation. Results of exact diagonalization of the critical PLBRM at b = 0.1, the banded random matrices with B=5, and Wigner-Dyson RM are shown in red, blue and green, respectively, and are represented by squares (N=200), circles (N=1000) and stars (N=2000).

The physical origin of the enhancement is two-fold: (i) a critical eigenfunction "occupies" only part of the available space which by normalization $\sum_{r} |\Psi(\mathbf{r})|^2 = 1$ enhances its amplitude, and (ii) the supports (the manifold of $\{\mathbf{r}\}$ where $|\Psi(\mathbf{r})|^2$ is essentially non-zero) of different critical eigenfunctions are strongly overlapping. It is important that both conditions are fulfilled simultaneously. For instance the condition (i) is fulfilled for localized states even better than for the critical ones but the lack of the condition (ii) levels off the gain in the correlation function $C(\omega)$. On the contrary, in a metal the condition (ii) is trivially fulfilled, but the eigenfunction amplitude is small.

III. OFF-CRITICAL STATES AND THEIR RANDOM MATRIX REPRESENTATIONS

Gaussian random matrix models proved to be an efficient and universal theoretical tool for describing complex systems. The success was partially due to the available analytical solutions^{5,7} and partially due to efficient algorithms of numerical diagonalization of matrices. Therefore it is highly desirable to have random matrix models that describe not only the critical MF eigenstates but also localized and extended eigenstates in the *vicinity* of the Anderson transition. The criterion to select such models is a qualitative and (when possible) a quantitative agreement with the results on the 3D Anderson model.



FIG. 2: 2D cartoon of a) conventional localized state; b) localized state in a multifractal insulator; c) extended state in a multifractal metal. The darker regions correspond to higher eigenfunction amplitude. The localization/correlation radius ξ is shown in each case.

As will be demonstrated below, the correlation function $C(\omega)$ in the 3D Anderson model contains the critical power-law behavior Eq.(6) well beyond the Anderson transition point. As a matter of fact the correlation function $C(\omega)$ is indistinguishable from the critical one until the dynamic length $L_{\omega} = 1/(\rho\omega)^{1/d}$ (ρ is the mean DoS) exceeds the localization/correlation length ξ . For $L_{\omega} > \xi$, or ω smaller than the level spacing in the localized volume $\delta_{\xi} \sim 1/(\rho\xi^d)$, the correlation function loses its critical features and shows typical features of a metal or an isulator.

This allows us to suggest the following cartoon of typical eigenfunctions in the vicinity of the localization transition shown in Fig.2. Namely, a typical localized state in a "multifractal insulator" can be viewed as a "piece of multifractal" of the size of the localization radius ξ (Fig.2b.), in contrast to a conventional localized state where all the localization volume is more of less homogeneously "filled" (Fig.2a.). In the same way, typical extended states on the metallic side of the localization transition ("multifractal metal") should look like a mosaic made of such "pieces of multifractal" (Fig.2c.).

Based on the persistence of the critical behavior beyond the critical region it is natural to assume that the random matrix model for the extended states near the critical point and the localized states on the other side of the transition should bear features of the critical RMT.

Let us start by constructing a random matrix model for the multifractal insulator. Given that the quasi-1D insulator is well described by the banded random matrices⁷ with exponentially decaying variance $\langle |H_{ij}|^2 \rangle = \exp\{-|i-j|/B\}$ we suggest the following hybrid RM model as a model for the multifractal insulator:

$$\langle |H_{ij}|^2 \rangle = \begin{cases} \beta^{-1}, & i = j \\ \frac{b^2}{2(|i-j|^2 + b^2)} \exp\{-(|i-j|/B)^\eta\}, & i \neq j \end{cases}$$
(8)

As compared with the critical PLBRM model Eq.(3), the model Eq.(8) contains an additional parameter B which sets in a finite localization radius $\xi(B)$. It also contains an exponent η which depends on the space dimensionality d of the disordered lattice model we would like to model by the RMT. In Sec.VIII we give both analytical and numerical arguments in favor of the choice

$$\eta = 1/d.$$

Another candidate has been suggested in Ref.¹⁴:

$$\langle |H_{ij}|^2 \rangle = \begin{cases} \beta^{-1}, & i = j \\ \frac{1}{2\left[1 + \left(\frac{|i-j|}{b}\right)^{2\alpha}\right]}, & i \neq j \end{cases}$$
(9)

In this case the localization radius ξ is controlled by the variable exponent α of the power-law. For a multifractal insulator $\alpha > 1$.

The possible RM models for multifractal metal are also constructed as deformations of the critical PLBRM. The model Eq.(9) for $\alpha < 1$ is believed¹⁴ to describe the multifractal metal. One can also think that the Gaussian RMT

$$\langle |H_{ij}|^2 \rangle = \begin{cases} \beta^{-1}, & i=j\\ \frac{1}{2\left[1 + \frac{|i-j|^2}{b^2}\right]} + (b/B)^2, & i \neq j \end{cases}$$
(10)

which is a hybrid of the critical PLBRM and the WD RMT, is also suitable for this purpose. Below we will study all those RM models in detail and compare the corresponding results for the correlation function $C(\omega)$ with the results obtained by numerical diagonalization of the *d*-dimensional Anderson model.

IV. ALMOST DIAGONAL GAUSSIAN RMT: ANALYTICAL RESULTS FOR $C(\omega)$

The characteristic properties of multifractal statistics of critical and off-critical states are best seen when the multifractality is strong. This is the case where the parameter $b \ll 1$ in Eqs.(3, 8, 9, 10) is small. On the other hand, this is exactly the limit where the typical off-diagonal elements of H_{ij} are small compared to diagonal ones. Such matrices (referred to as *almost diagonal* random matrices (ADRM)) may possess a non-trivial statistics of eigenfunctions which justifies their special study^{25,27}. The idea of analytical treatment of ADRM, first suggested in Ref.²⁶ and used in²¹ to compute the correlation dimension d_2 for the critical PLBRM model Eq.(3), is similar to the virial expansion in dilute gases. However, instead of taking into account two-, three- and multiple-particle collisions, one considers progressively increasing number of interacting resonance sites coupled by a small off-diagonal matrix element H_{ij} . Recently the virial coefficients for the Gaussian ADRM with an arbitrary (but small) variance $\sigma^2(|i - j|) = 2\langle |H_{ij}|^2 \rangle$ were expressed through the supersymmetric field theory²⁷ and the correlation function $C(\omega)$ has been explicitly calculated in the two-state approximation for the *unitary* symmetry class $\beta = 2$. The result is the following:

$$C(\omega) = \frac{k(\omega)}{N r(\omega)},\tag{11}$$

where

$$k(\omega) = \sum_{n=1}^{N} \left[\left(2\bar{\omega} + \frac{1}{\bar{\omega}} \right) e^{-\bar{\omega}^2} \frac{\sqrt{\pi}}{2} \operatorname{Erfi}\left(\bar{\omega}\right) - 1 \right], \quad (12)$$

and

$$r(\omega) = \frac{\sqrt{\pi}}{N} \sum_{n=1}^{N} \bar{\omega} e^{-\bar{\omega}^2} \operatorname{Erfi}\left(\bar{\omega}\right).$$
(13)

In Eqs.(12,13) we denote

$$\bar{\omega} = \frac{\omega}{\sqrt{2\sigma^2(n)}} = \frac{\omega}{2\sqrt{\langle |H_{i,i+n}|^2 \rangle}}.$$
 (14)

and $\operatorname{Erfi}(z) = \frac{2}{\sqrt{\pi}} \int_0^z e^{t^2} dt.$

The result given by Eqs.(12,13) is valid in the limit when:

$$\sum_{n=1}^{N} \sigma(n) \ll \sqrt{\langle |H_{ii}|^2 \rangle}.$$
(15)

For the RMT defined by Eq.(8) and Eq.(9) with $\alpha > 1$ which are suggested to describe the multifractal insulator, the sum over n in Eq.(15)converges. Then the validity of Eqs.(12,13) is independent of the matrix size Nin the limit $N \to \infty$ and is controlled only by a small parameter $b \ll 1$. On the contrary, for the models of the multifractal metal described by Eq.(10) and Eq.(9) with $\alpha < 1$ the sum in Eq.(15) diverges at large N. Then Eqs.(12,13) are only valid for $N < \xi$ where we define the correlation radius ξ as follows:

$$\sum_{n=1}^{\xi} \sigma(n) = \sqrt{\langle |H_{ii}|^2 \rangle}.$$
(16)

We will show below that a good qualitative description of the metal phase in the limit $N \to \infty$ can still be obtained from the above theory if one substitutes ξ for Nin Eqs.(12,13).

Eqs.(12)-(16) will be used throughout the paper to analize different random matrix ensembles suggested as possible models for critical eigenstates and the off-critical states in a multifractal metal and insulator.

V. TWO EIGENFUNCTION CORRELATIONS AT CRITICALITY

It is not a priori clear that the critical power-law behavior Eq.(6) and the dynamical scaling relationship Eq.(7) hold true for all systems where Eq.(5) is valid. In particular it is interesting to study the correlation function Eq.(2) in the limit of strong multifractality when $d_2 \rightarrow 0$. Below we will derive an *analytical* formula for the critical PLBRM in the limit $b \rightarrow 0$ which corresponds²⁰ to $d_2 \rightarrow 0$ and confirm the scaling law Eq.(7) by numerical diagonalization of PLBRM with very small b.

One can easily see from Eqs.(12)-(14) in which we plug in Eq.(3) that in the interval $\frac{b}{N} \ll |E - E'| \ll b$ the correlation function $C(\omega)$ given by these equations has an asymptotic power law behavior Eq.(6) with $\mu = 1$:

$$NC(\omega) = \frac{E_0}{|\omega|}, \quad E_0 = \left(\frac{\pi}{2}\right)^{3/2} b.$$
 (17)

Applying Eq.(15) to the critical PLBRM Eq.(3) gives the criterion of validity $\ln N \ll 1/b \sim 1/d_2$ in which case one cannot distinguish between N^{1-d_2} and N, or, correspondingly, between ω^{-1+d_2} and $1/\omega$. Thus the analytical formulae Eqs.(12,3) is consistent with the scaling relationship Eq.(7), given that $d_2(b) \to 0$ as $b \to 0$.

A comparison of the analytical results and the results of numerical diagonalization of the critical PLBRM with $\beta = 2$ and b = 0.06 is shown in Fig.3. The coincidence is very good for large energy separations. The deviation at small energy separations is due to the difference in the values of μ . The exponent $\mu = 1$ for the analytical curve and $\mu = 0.86$ for the numerical curve which is very close to the prediction of Eq.(7) $\mu = 1 - d_2 \approx 0.865$, where d_2 is found from the numerical data for $P_2(N)$ and Eq.(5).

The scaling relationship Eq.(7) is further checked in Fig.4 where the numerical data for μ and $1 - d_2$ is plotted as a function of b. The fulfillment of this relationship down to b as small as 0.005 and an agreement with the theoretical prediction of Ref.²¹ is spectacular. Thus from the combination of analytical and numerical results we conclude that the Chalker's scaling Eqs.(6),(7) is valid for arbitrary small b and thus for arbitrary strong multi-fractality.

Finally we demonstrate how well the critical PLBRM Eq.(3) describes the two-eigenfunction correlations in the 3D Anderson model at the mobility edge. To this end we modify the distribution of the on-site energies in the Anderson model from the standard rectangular box distribution to the triangular distribution where the mobility edge corresponds to $E_c = \pm 3.5$. The correlation function $C(\omega)$ with E, E' near the mobility edge is shown in Fig.5. It coincides almost exactly with the corresponding curve resulting from numerical diagonalization of the critical PLBRM ensemble with only one fitting parameter b = 0.42.





FIG. 4: The scaling relationship between μ and d_2 for the $\beta = 2$ critical PLBRM. The solid line is the prediction based on Ref.²¹ $d_2 = \frac{\pi}{\sqrt{2}}b$.

FIG. 3: Two-eigenfunction correlation function $C(\omega)$ for the critical PLBRM with $\beta = 2$, b = 0.06 and N = 200(square),1000(circle) and 2000 (star). The analytical curve at N = 2000 given by Eqs.(11-13) is shown by a solid line.

VI. EIGEFUNCTION MUTUAL AVOIDING AND STRATIFICATION OF COORDINATE SPACE

Results of both numerical and analytical calculation presented in Fig.3 reveal another unexpected feature of eigenfunction correlation which appears to be common to all ADRM. Surprisingly it is also present for the 3D Anderson model both in the metal and in the insulator phase (see Fig.6). This is the *negative* eigenfuncton correlations for $\omega = |E - E'| > E_0 \sim b$. Indeed, one can see from Fig.3 and Fig.6 that for large enough ω the correlation function $C(\omega)$ goes below the uncorrelated limit $C(\omega) = 1/N$ which corresponds to $\langle |\Psi_i|^2 |\Psi_j|^2 \rangle = \langle |\Psi_i|^2 \rangle \langle |\Psi_j|^2 \rangle = 1/N^2$. We denote by E_0 the value of ω where this limit is reached. For $\omega > E_0$ the correlation function $C(\omega) \propto 1/\omega^2$ decreases down to zero. Such a behavior implies that two eigenfunctions separated by an energy difference $\omega > E_0$ try to avoid each other. That is, if a site \mathbf{r} is occupied in one of the states it should be predominantly empty in the other.

To explain such a behavior the following cartoon is useful. Let us define a *support* of an eigenfunction as the manifold of sites $\{\mathbf{r}\}$ where $|\Psi_i(\mathbf{r})|^2$ is essentially nonzero. To construct such a support starting from a given site \mathbf{r} with the on-site energy $\varepsilon_{\mathbf{r}}$ we find all the sites in resonance with the site \mathbf{r} , i.e. such sites \mathbf{r}' which onsite energies $\varepsilon_{\mathbf{r}'}$ obey the relationship $|\varepsilon_{\mathbf{r}'} - \varepsilon_{\mathbf{r}}| < |H_{\mathbf{r},\mathbf{r}'}|$.



FIG. 5: Two-eigenfunction correlation function for the 3D Anderson model (orthogonal symmetry class) with a triangular distribution of random on-site energies (solid symbols) and the critical PLBRM Eq.(3) with $\beta = 1$ and b = 0.42 (open symbols). The energy difference $\omega = |E - E'|$ is measured in units of mean level spacing. The insert shows the mean density of states; the mobility edge corresponds to $\varepsilon = \pm 3.5$. The energies E, E' were taken from the window (3.3, 3.7) for the 3D Anderson model and (-0.2, 0.2) for the critical PLBRM. The slope of the critical power-law Eq.(6) is 0.52 in both cases which corresponds to $d_2/d = 0.48$.



FIG. 6: Eigenfunction avoiding for the PLBRM with b=0.42(stars), 3D Anderson insulator (red triangles) and metal (blue triangles). The dotted line corresponds to the limit of uncorrelated eigenfunctions; the solid line corresponds to the power law $1/\omega^2$. Points below the dotted line correspond to eigenfunction avoiding.



FIG. 7: A cartoon of stratification of the coordinate space: different non-intersecting supports shown by different colours. Each support corresponds to a shell of states occupying this support and thus strongly overlapping; states belonging to different shells do not overlap. The stratification of space explains both strong correlations of states at energy separation ω smaller that the single-shell bandwidth E_0 and mutual avoiding of eigenstates for $\omega > E_0$.

Then the procedure should be repeated for all sites \mathbf{r}' and so on. It is important that so obtained manifold $\{\mathbf{r}\}$ does not always include all the sites of the system. If this is the case, the whole coordinate space is *stratified* into a set of mutually non-intersecting supports (Fig.7).

Once the support is defined, one can build a *shell* of states on this support by making a linear combination of on-site states, pretty much in the same way as in build-

ing the conduction band states out of the on-site states in the tight-binding model. Then by construction the eigenfunctions belonging to the same shell are well overlapping but those belonging to different shells do not overlap.

From this cartoon it is clear that the physical meaning of the scale E_0 is the width of the energy band corresponding to a single shell. Indeed, if the energy separation ω greatly exceeds the typical single shell bandwidth, the two eigenfunctions must belong to different shells and thus do not significantly overlap in space. On the contrary, if ω is smaller than the single shell bandwidth, the two states typically belong to the same shell and thus overlap strongly no matter how sparse the shell support.

The new energy scale E_0 , which is the upper energy cut-off of the multifractal correlations, corresponds to a new length scale

$$\ell_0 = \frac{1}{(\rho E_0)^{1/d}},\tag{18}$$

which has a meaning of the minimum length scale of the fractal texture. In the *d*-dimensional Anderson model the energy scale E_0 can be estimated as

$$E_0 \sim V \sim D/W_c \sim D/(2d\ln 2d),$$

where D is the total bandwidth. Estimating the DOS as $\rho = 1/(a^3D)$ we find $\ell_0 \sim a W_c^{1/d}$, where a is the lattice constant.

Clearly the picture with a stratified coordinate space is possible for PLBRM Eq.(3) with small enough b < 1when the single shell bandwidth $E_0 \sim b$ is small compared to the total bandwidth ~ 1 . Amazingly, the 3D Anderson model which low-frequency critical features are well described by the critical PLBRM with $b \approx 0.42$, also follows the predictions of the critical PLBRM for high frequencies $\omega > E_0$. This is a consequence of a relatively large value $W_c = 16.5$ of the critical disorder which results in E_0 considerably smaller than the conduction bandwidth D. In particular its coordinate space must be stratified to explain the observed (see Fig.6) mutual avoiding of eigenstates.

VII. THE MULTIFRACTAL INSULATOR

As has been demonstrated in Sec.V critical eigenfunctions with $\xi > L$ are strongly correlated in space. Here we consider the case of multifractal insulator where the localization radius ξ is large compared to relevant microscopic lengths (the lattice constant or elastic scattering length) but is much smaller than the system size L. We will identify a suitable random matrix model to describe this case and compare the properties of eigenfunction correlation in this model with those of the 3D Anderson model.



FIG. 8: Eigenfunction correlation in the 1D Anderson insulator with rectangular distribution of on-site energies and periodic boundary conditions. The disorder strength is W = 5 (circles), W = 10 (stars). The inverse participation ratio is equal to 0.23 and 0.46, respectively.

A. The ideal insulator limit

We start by considering a limit of strong disorder when the localization length $\xi \sim 1$ and the multifractal nature of eigenstates does not show up. A common wisdom is that in the strongly localized regime the positions of the localization centers are completely uncorrelated. As it is shown in the Introduction, this leads to

$$NC(\omega) = 1, \tag{19}$$

which we will refer to as the *ideal insulator limit*. Fig.1 shows how this limit is reached in the ensemble of banded random matrices.

Note that $C(\omega)$ in this limit is much smaller than the self-overlap of $|\Psi(\mathbf{r})|^2$ given by the inverse participation ratio Eq.(4). Only for very small energy separations (typically $\propto e^{-L/\xi}$) which we will not be considering here, the IPR limit can be approached.

Now let us see how does the correlation function $C(\omega)$ look like for the strong Anderson insulator. The corresponding plot for 1D Anderson model is shown in Fig.8. It coincides almost exactly with the ideal insulator limit Eq.(19).

The plot for the 3D Anderson model is shown in Fig.9. On can see that $NC(\omega)$ is significantly enhanced at small energy separations and does not resemble at all the correlation function in 1D Anderson insulator.



FIG. 9: Eigenfunction correlation in the 3D Anderson insulator with rectangular distribution of on-site energies and periodic boundary conditions. The disorder strength is W = 80(green), W = 60 (blue), W = 40 (red), W = 30 (purple). The system size is L = 20 for filled symbols and L = 8 for open symbols. The inverse participation ratio for the four insulating systems is $P_2 = 0.72$, 0.63, 0.44, 0.28 which corresponds to $\xi = 1.0$, 1.1, 1.2, 1.4 according to $\xi = (9/4\pi P_2)^{1/3}$. The change of the slope occurs at $|E - E'| = \delta_{\xi}$. The slope for larger energy separations $|E - E'| > \delta_{\xi}$ progressively increases with increasing W remaining smaller than 1. The insert shows the result for W = 60, L = 20 for the periodic (upper blue curve) and the hard wall (lower red curve) boundary conditions.

B. Repulsion of centers of localization for $R \gg \xi$

In order to understand why the ideal insulator limit is not reached in the 3D case despite the ratio $\xi/L > 10$ we compute numerically the probability distribution (PDF)

$$F_{\omega}(R) = \langle \delta(\omega - E_n + E_m) \, \delta(R - |\mathbf{r}_n - \mathbf{r}_m|) \rangle \qquad (20)$$

of the distance $R = |\mathbf{r}_n - \mathbf{r}_m|$ between the points \mathbf{r}_n and \mathbf{r}_m in real space (centers of localization) where $|\Psi_{n,m}(\mathbf{r})|^2$ has an absolute maximum, provided that the energy separation between the states n, m is ω .

The results are shown in Fig.10. It is seen that the function $F_{\omega}(R)$ is far from being independent of R (which would imply the lack of correlations between centers of localization). In fact, there is a *repulsion of centers of localization* at distances $R < R_0 \sim 12$ which shows up in the decreasing probability density to find two centers of localization close to each other. Note that R_0 is almost 10 times larger than the localization radius ξ estimated from the inverse participation ratio P_2 .



FIG. 10: The probability density Eq.(20) of having two centers of localization at a distance R in real space and at a distance ω in the energy space computed for the 3D Anderson model in the strong localization regime ($W = 60, \xi = 1.1, L = 20$). The repulsive core $R_0 \sim 10 - 12$ exceeds the "hard ball" limit 2ξ by a factor of 5-6.

An explanation to this fact of repulsion between centers of localization $\mathbf{r_n}$ and $\mathbf{r_m}$ is based on the resonance interaction between states $\Psi_n(\mathbf{r})$ and $\Psi_m(\mathbf{r})$ if the energy distance between them is smaller than the typical overlap integral $V_{nm}(R) \propto e^{-R/2\xi}$.

The size of the repulsion core R_0 can be estimated from the equation:

$$V_{nm}(R_0) = \omega, \quad \Rightarrow R_0 \sim 2\xi \, \ln\left(\frac{\delta_{\xi}}{\omega}\right).$$
 (21)

The characteristic energy scale δ_{ξ} is the mean level separation for states localized in the same volume ξ^d . Thus the repulsion of centers of localization is a direct consequence of repulsion of energy levels for states confined in the same volume ξ^d . The energy scale δ_{ξ} depends on the strength of disorder and is of the order of the Fermi energy for strongly localized states. At $\omega \ll \delta_{\xi}$ the size of the repulsion core R_0 may considerably exceed the localization radius.

The qualitative picture of repulsion of centers of localization can be quantitatively confirmed using the analytical theory Eqs.(11-14) for the almost diagonal Gaussian RMT. To this end we look at the contribution of $\bar{\omega} \gg 1$ to the sum in Eq.(12). Replacing the summation over nby integration we obtain the contribution to $NC(\omega)$:

$$\int_{\sigma(n)<\omega} \frac{2\sigma^2(n)}{\omega^2} \, dn. \tag{22}$$

This equation can be easily interpreted using an elementary perturbation theory. Indeed, for strongly localized states $\Psi_m(\mathbf{r}_n)$ the eigenfunction correlation function can be represented as follows:

$$C_{nm} = \sum_{\mathbf{r}} |\Psi_n(\mathbf{r})|^2 |\Psi_m(\mathbf{r})|^2 \approx$$
(23)
$$\approx |\Psi_m(\mathbf{r_n})|^2 \sum_{\mathbf{r}} |\Psi_n(\mathbf{r})|^2 + |\Psi_n(\mathbf{r_m})|^2 \sum_{\mathbf{r}} |\Psi_m(\mathbf{r})|^2$$
$$\approx |\Psi_m(\mathbf{r_n})|^2 + |\Psi_n(\mathbf{r_m})|^2.$$

The amplitude at the tail of the wavefunction $|\Psi_n(\mathbf{r_m})|^2$ with the maximum at a point \mathbf{r}_n can be computed from the elementary perturbation theory in which the wavefunction of the zero-th approximation corresponding to the energy ε_n is $|\Psi_n^{(0)}(\mathbf{r})|^2 = \delta_{\mathbf{r},\mathbf{r}_n}$:

$$|\Psi_n(\mathbf{r_m})|^2 = |\Psi_m(\mathbf{r_n})|^2 \approx \frac{|H_{nm}|^2}{(\varepsilon_n - \varepsilon_m)^2} \approx \frac{|H_{nm}|^2}{\omega^2} \ll 1.$$
(24)

The fluctuating *on-site* energy ε_n is the main part of the eigenvalue E_n for a sufficiently strongly localized state. Thus we come to a conclusion that the amplitude of the wavefunction Ψ_n at a center of localization of the wavefunction Ψ_m is inversely proportional to $(E_n - E_m)^2 = \omega^2$ and thus is strongly enhanced when $\omega \ll \delta_{\xi}$. At the first glance this is in a contradiction with the common wisdom that $|\Psi_n(\mathbf{r}_m)|^2 \propto e^{|\mathbf{r}_n-\mathbf{r}_m|/\xi}$ which is apparently ω -independent. The point is that the quantity $|\Psi_n(\mathbf{r})|^2$ has many accidental spikes due to resonances between on-site energies. The measure of such resonance points is small and for some (but not all) purposes one can neglect them and to approximate $|\Psi_n(\mathbf{r})|^2 \propto e^{|\mathbf{r}_n - \mathbf{r}_m|/\xi}$. The best known example when the two-spike eigenfunction makes the main contribution is the low-frequency conductivity in the localized phase²⁸. As we will see below, here we deal with a very similar phenomenon.

Now the correlation function $C(\omega)$ can be computed just by averaging over disorder and the distance $\mathbf{R} = \mathbf{r}_n - \mathbf{r}_m$:

$$C(\omega) = \int F_{\omega}(R) \langle C_{nm}(R) \rangle d^{d}R \qquad (25)$$
$$\approx \int F_{\omega}(R) \frac{2\langle |H_{nm}|^{2} \rangle}{\omega^{2}} d^{d}R,$$

where $F_{\omega}(R)$ is the PDF defined by Eq.(20).

Comparing Eq.(25) for d = 1 with Eq.(22) we see that:

$$F_{\omega}(R) = 1/N, \quad (R \gg R_0), \tag{26}$$

where R_0 is found from the condition $\sigma(R_0) = \omega$ similar to Eq.(21).

In the opposite limit $R \ll R_0$, or $\omega \ll \sigma(R)$, we have a resonance enhancement $|\Psi_m(\mathbf{r}_n)|^2 \approx 1/2$ and $C_{nm} \approx 1$. Then the comparison of Eq.(25) with Eq.(12) yields:

$$F_{\omega}(R) = \frac{4}{3N} \left(\frac{\omega}{\sigma(R)}\right)^2, \quad (R \ll R_0).$$
(27)



FIG. 11: A comparison of eigenfunction correlation functions for 3D Anderson model with W = 30, L = 20 and the truncated critical RMT Eq.(7) with b = 0.42, B = 5, $\eta = 1/3$ and N = 2000. The IPR takes values of $P_2 = 0.28$ and 0.25, respectively. The scale of $\omega = |E - E'|$ is different in those two cases by approximately a factor of 11.

C. Logarithmic enhancement of correlations of localized eigenfunctions and the Truncated Critical RMT

Now let us consider Eq.(25) for $d \geq 1$ assuming that all states are exponentially localized and thus $\langle |H_{nm}|^2 \rangle \propto \exp[-R/\xi]$. We also assume for simplicity that $F_{\omega}(R) = N^{-1} \theta(R - R_0)$, where $R_0 = 2\xi \ln(\delta_{\xi}/\omega)$. Then one immediately obtains from Eq.(25) that due to the phase volume factor R^{d-1} the correlation of exponentially localized eigenfunctions depends crucially on the dimensionality of space. Namely, for d = 1 the ideal insulator limit Eq.(19) is reached for sufficiently small ξ (see Fig.1), while for d > 1 and $\omega \ll \delta_{\xi}$ the correlation function acquires a logarithmic in ω enhancement factor:

$$NC(\omega) \sim \xi^{d-d_2} \ln^{d-1}\left(\frac{\delta_{\xi}}{\omega}\right).$$
 (28)

The physics behind this result is similar to the one which leads to the selebrated Mott's $law^{28,29} \sigma(\omega) \propto \omega^2 \ln^{d+1}(\delta_{\xi}/\omega)$ for the ac conductivity $\sigma(\omega)$ at $\omega \ll \delta_{\xi}$. The difference is that the contribution to conductivity from the resonance states with the distance R between the points of maximal amplitude is proportional to the square of the dipole moment $d^2 \propto R^2$, so that the phase volume factor R^{d-1} gets multiplied by R^2 resulting in emergence of the logarithmic factor $\ln^{d+1}(\delta_{\xi}/\omega)$ instead of $\ln^{d-1}(\delta_{\xi}/\omega)$ in our case.

Below we obtain this result for the *truncated critical* RMT defined by Eq.(8). The phase volume factor R^{d-1}

can be formally taken into account in the random matrix formalism Eq.(12) if one assumes the following relationship between the *d*-dimensional vector \mathbf{R} and the difference of matrix indices n - m:

$$d(n-m) \Rightarrow \Omega_d R^{d-1} dR, \quad |n-m| \Rightarrow \frac{\Omega_d}{d} R^d, \quad (29)$$

where Ω_d is the total solid angle in the *d*-dimensional space.

In particular Eq.(29) suggests that for exponential localization the correct truncating factor in Eq.(8) has the form:

$$e^{-R/\xi} \Rightarrow \exp\left[-\left(\frac{|n-m|}{B}\right)^{1/d}\right].$$
 (30)

This sets the exponent η in Eq.(8) equal to:

$$\eta = \frac{1}{d}.\tag{31}$$

Then Eq.(12) can be used which is convenient to rewrite in the following form:

$$NC(\omega) \approx k(\omega) = -\int_0^\infty f(y) \, \frac{dy}{\frac{d}{dn} (\ln \sigma^2(n))|_{n=n(y)}}, \quad (32)$$

where n(y) is found from the equation

$$y = \frac{\omega^2}{2\sigma^2(n(y))}$$

and

$$f(y) = \left(\frac{2}{\sqrt{y}} + \frac{1}{y\sqrt{y}}\right) e^{-y} \int_0^{\sqrt{y}} e^{t^2} dt - \frac{1}{y} = \begin{cases} \frac{4}{3}, & y \ll 1\\ \frac{1}{y^2}, & y \gg 1 \end{cases}$$
(33)

For the truncated critical RMT Eq.(8) with $\eta = 1/d$ one finds:

$$-\frac{1}{\frac{d}{dn}(\ln\sigma^2(n))} = \frac{n}{2 + \frac{1}{d}\left(\frac{n}{B}\right)^{1/d}},$$

where

$$n(y) = \begin{cases} B \ln^d \left(\frac{2b^2 y}{\omega^2 B^2}\right), & \frac{\omega}{\sqrt{y}} \ll \delta_{\xi} \sim \frac{b}{B} \\ \sqrt{\frac{2b^2 y}{\omega^2}}, & \frac{\omega}{\sqrt{y}} \gg \delta_{\xi} \end{cases}$$
(34)

The integral in Eq.(32) is well convergent and thus mainly contributed by $y \sim 1$. This makes it possible to obtain a simple analytical expression for $NC(\omega)$:

$$NC(\omega) \approx \begin{cases} c_d B \, \ln^{d-1}\left(\frac{\delta_{\xi}}{\omega}\right), & \omega \ll \delta_{\xi} \sim b/B \\ c_0\left(\frac{b}{\omega}\right), & E_0 \sim b \gg \omega \gg \delta_{\xi} \end{cases}$$
(35)

where

$$c_d = 2^{d-1}d \int_0^\infty f(y)dy = 2^d d$$

$$c_0 = \int_0^\infty f(y) \sqrt{\frac{y}{2}} = \left(\frac{\pi}{2}\right)^{\frac{3}{2}} \approx 1.97.$$

The first line of Eq.(35) is consistent with Eq.(28) in which $d_2/d \sim b \ll 1$ and $\xi \sim B^{1/d}$. The power-law behavior in the second line of Eq.(35) is a remnant of the critical behavior Eq.(6). It exists only for considerably large $B \gg 1$ where $\delta_{\xi} \ll E_0 = c_0 b$, i.e. only in the *multifractal* insulator. For a very strong insulator with $\delta_{\xi} \gg E_0$, the localization radius is smaller than the minimal length scale ℓ_0 of the fractal texture. This is the region of an ordinary insulator where the entire localization volume is more or less homogeneously filled.

Thus the eigenfunction correlation function for the truncated critical RMT Eq.(8)interpolates between the behavior given by Eq.(28) at $\omega \ll \delta_{\xi}$ (or $L_{\omega} = (\rho \omega)^{-1/d} \gg \xi$) and the critical behavior Eq.(6) which is valid for $\ell_0 \ll L_{\omega} \ll \xi$. At $L_{\omega} \sim \xi$ both asymptotic forms are apparently matching with each other.

The physical picture that leads to such a behavior is the following. There are two distinct regions $L_{\omega} < \xi$ and $L_{\omega} > \xi$ where physics of eigenfunction correlations is entirely different. In the case $L_{\omega} < \xi$ the characteristic length L_{ω} has a meaning of the period of beating in the overlap of two fractal eigenfunctions inside the localization volume. The regions where two fractal supports match well with each other alternate with the regions with a strong mismatch between them, very much like in the case of two grids with slightly different periods. The regions of strong overlap make the main contribution

$$C_m \sim P_2 \sim (L_\omega/\ell_0)^{d-d_2}/\xi^d$$

to the eigenfunction correlation function $C(\omega)$ which is of the order of the IPR of a multifractal metal (see next Section for more details) with the system size equal to the localization radius ξ and the correlation length equal to the size L_{ω} of the well overlapping regions. To obtain the correlation function $C(\omega)$ one has to multiply $C_m(\omega)$ by the probability for the entire localization volumes to overlap. This probability is ξ^d/L^d , as for $\omega > \delta_{\xi}$ there is no correlations in the positions of the localization volumes. Thus we obtain the critical power-law Eq.(6): $NC(\omega) \sim (L_{\omega}/\ell_0)^{d-d_2} = (E_0/\omega)^{1-d_2/d}$.

For $L_{\omega} > \xi$ physics of eigenfunction correlations changes drastically. Now localization volumes are statistically repelling each other and the overlap is only due to the tails. In this region the length scale L_{ω} loses its physical meaning which is taken over by the length scale R_0 given by Eq.(21).

The overall shape of $C(\omega)$ with the logarithmic enhancement factor $\ln^{d-1}(\delta_{\xi}/\omega)$ obtained within the Truncated Critical RMT describes the numerical results on the 3D Anderson model very well (see Fig.11). The absence of this factor at d = 1 explains the qualitative difference between the case d = 1 (see Fig.8) and d = 3 (see Fig.9). This difference is essentially due to a competition between two effects (i) repulsion of centers of localization and (ii) resonance enhancement of overlap by tails. The

first effect tends to decrease the probability of the overlap of localization volumes. The second effect increases the eigenfunction overlap by means of tails. In the 1D case these two effects compensate each other and the result is the same as one would obtain for completely uncorrelated positions of localization volumes and the typical exponentially decreasing tails. In higher dimensions the enhancement of overlap in the tail region prevails because of the increased volume of those regions.

Concluding this subsection we claim that the truncated critical RMT provides an excellent description of the 3D Anderson insulator both in the strong localization region (see Fig.9) and in the region of multifractal insulator where the localization radius is large and the corresponding scale δ_{ξ} is small compared with the upper cutoff E_0 of multifractal correlations. Because of the limited size of the 3D lattice this latter region is out of reach for numerical simulations on the 3D Anderson model, and the random matrix theory is the only mathematical model which properly describes physics of the multifractal insulator.

D. Super-critical PLBRM

Note that there is another RMT Eq.(9) suggested in Ref.¹⁴ as a candidate to describe eigenfunction correlations in the multifractal insulator. Below we show that this *super-critical* PLBRM is principally flawed, as it corresponds to a power-law localization which is not the case in the 3D Anderson model.

This can be best demonstrated by Eq.(24) in which $|H_{nm}| \Rightarrow \sigma(R) = (b/R)^{\alpha}$ with $\alpha > 1$. Accordingly, the typical scale for the repulsion of centers of localization is:

$$R_{\omega} = \frac{b}{\omega^{1/\alpha}}.$$
 (36)

In Fig.12 we plot the results of numerical calculation of the PDF $F_{\omega}(R)$ for the super-critical PLBRM Eq.(9). The characteristic scale R_{ω} where $F_{\omega}(R)$ reaches its maximum, is well seen in this plot.

The analytical treatment based on Eq.(32) yields for this model:

$$NC(\omega) = \left(\frac{E_{\alpha}}{\omega}\right)^{\frac{1}{\alpha}} \sim R_{\omega}, \qquad (37)$$

where $E_{\alpha} = (c_{\alpha}b)^{\alpha}$, and

$$c_{\alpha} = \frac{\pi^{3/2}}{2^{1+\frac{1}{2\alpha}}} \frac{1}{\Gamma(\frac{3}{2} - \frac{1}{2\alpha})}.$$

As well as the entire approach based on Eq.(12), the above results are valid when b is the smallest relevant parameter. In the problem of PLBRM with α close to 1, there is a competition between the small parameters $|1-\alpha|$ and b, so that the validity of Eqs.(36),(37) requires also $\alpha - 1 \gg b$.



FIG. 12: The correlation function of centers of localization $F_{\omega}(R)$ for the super-critical PLBRM Eq.(9) with $\alpha = 1.1$, b = 0.1, N = 1000 for $\omega = 0.011$ (black), 0.0035 (blue), 0.0015 (green). The insert shows the ω -dependence of R_{ω} where $F_{\omega}(R)$ reaches its maximum. The finite slope of $F_{\omega}(R)$ for $R \gg R_{\omega}$ is a finite size effect which was neglected in Eq.(26).

We see that in the infinite system $N \to \infty$ the powerlaw Eq.(37) in $C(\omega)$ is not restricted at small ω , and no energy scale similar to δ_{ξ} emerges. This can be explained only if we assume that the localization length for $\alpha - 1 >>$ b is of order one. Then for all energy separations $\omega \gg E_{\alpha}$ the repulsion core $R_{\omega} \gg \xi$, and no qualitative change in the correlation function occurs until R_{ω} hits the system size N. For smaller ω the correlation function is almost a constant. This quantitative analysis is illustrated by Fig.13.

The region of α that could describe the multifractal insulator with large $\xi \gg 1$ corresponds to $\alpha - 1 \ll b$. In this case an energy scale similar to δ_{ξ} should appear. It can be found from the condition

$$R_{\omega}|_{\omega=\delta_{\xi}} = \xi(\alpha), \quad \Rightarrow \delta_{\xi} \approx \frac{E_0}{\xi}.$$
 (38)

At $|E - E'| = \delta_{\xi}$ the slope on the log-log plot of $C(\omega)$ should change from the critical value at $\delta_{\xi} < |E - E'| < E_0$ to a different (but constant) α -dependent value at $|E - E'| < \delta_{\xi}$. This change of the slope is clearly seen in the numerical simulations on the super-critical PLBRM presented in Fig.14. It appears that in all cases studied the slope μ at $|E - E'| < \delta_{\xi}$ is *larger* than that at $|E - E'| > \delta_{\xi}$. This is in a clear contradiction with the results (see Fig.9) obtained in the 3D Anderson insulator.

An important conclusion we can draw from the above analysis of the super-critical PLBRM is that the correlation function $C(\omega)$ for $\omega < \delta_{\xi}$ is the power-law in this



FIG. 13: Two-eigenfunction correlation for the super-critical PLBRM Eq.(9) with $\alpha - 1 >> b$ calculated analytically using Eqs.(11-14). The power law $C(\omega) \propto \omega^{-1/\alpha}$ is valid for all energy separations corresponding to $1 < R_{\omega} < N$. The onset of the plateau moves to $\omega \to 0$ in the limit $N \to \infty$. The ideal insulator limit is reached by decreasing the slope with increasing α .



FIG. 14: Two-eigenfunction correlation for the super-critical PLBRM Eq.(9). Numerical results for $\alpha - 1 < b$ (this plot corresponds to $\alpha = 1.15$, b = 0.45, N = 5000) show that the exponent μ of the power-law $C(\omega) \propto \omega^{-\mu}$ changes at $|E - E'| = \delta_{\xi}$ with the larger value corresponding to smaller energy separations.

model. This can be traced back to the power-law character of localization in the super-critical PLBRM which is not the case in the disordered lattice models (such as the 3D Anderson model) with short-range hopping integrals. This is the reason why the super-critical PLBRM is not suitable to describe the insulating phase of the 3D

VIII. SEARCH FOR RANDOM-MATRIX MODEL FOR A MULTIFRACTAL METAL

A. Anti-truncated critical RMT

Surprisingly, the natural counterpart to the truncated critical RMT Eq.(8) which is defined by Eq.(10) ("antitruncated" critical RMT) does not describe extended states in the multifractal metal. The reason is that this model possesses *two* low-frequency system-size independent energy scales instead of the single scale δ_{ξ} which is associated with the size ξ of a multifractal cell in Fig.2c. In order to see this we analyze the analytical formulae Eqs.(11-14) with the variance defined by Eq.(10).

To this end we expand the summand of Eq.(12) in $1/\bar{\omega} \ll 1$ to arrive at the formula similar to Eq.(22) but with the upper limit of integration equal to the correlation radius ξ :

$$NC(\omega) = \frac{2}{\omega^2} \int_{\sigma(n) < \omega}^{\xi} \sigma^2(n) \, dn.$$
 (39)

where $\xi = B/2b$ according to Eq.(16).

Substituting Eq.(10) for $\sigma(n)$ we arrive at:

$$NC(\omega) = \frac{b^2}{\omega^2} \int_{b/\omega}^{\xi} \left[\frac{1}{n^2} + \frac{2}{B^2} \right] \approx \frac{b}{\omega} + 2\xi \frac{b^2}{\omega^2 B^2}.$$
 (40)

Eq.(40) is valid at $\omega > b/\xi$ when the upper limit of integration is larger than the lower limit. This sets the energy scale $\omega_1 = b/\xi = 2b^2/B$.

Another scale $\omega_2 = 1/(2b\xi)$ gives the cross-over scale that separates the critical $1/\omega$ behavior and the $1/\omega^2$ behavior that takes place for indermediate frequencies $\omega_1 < \omega < \omega_2$. While the scale $\omega_1 = b/\xi$ (similar to the scale $\delta_{\xi} = b/B$ in a 1D insulator) determines the onset of the low-frequency plateau, the second relevant scale ω_2 that appears in the model Eq.(10) seems to have no physical meaning. Indeed, the existence of this scale leads to a characteristic form of the correlator $C(\omega)$ which log-log plot has a significant slope increase just before it drops to zero at the plateau (see Figs.15, 16).

We did not find the behavior of such type in the 3D Anderson metal (see Fig.17). The plot in Fig.17 clearly shows a saturation³⁰ at $\omega < \omega_1$:

$$C(\omega) \approx \frac{1}{3}P_2 = A_m \frac{\xi^{d-d_2}}{3L^d}, \quad A_m \approx 0.5.$$
 (41)

However, there is no evidence of a maximum in the slope just above the onset of the plateau.

B. Sub-critical PLRBM

Now we consider the sub-critical PLBRM ensemble defined by Eq.(9) with $1/2 < \alpha < 1$. In this case analytical



FIG. 15: Numerics on the anti-truncated critical RMT of the orthogonal symmetry class. The predicted analytically non-monotonous behavior of log-log slope controlled by the energy scale ω_2 is well seen both for small and large system sizes. The solid line is a fit according to Eq.(40).



FIG. 16: Eigenfunction correlation for the anti-truncated critical RMT Eq.(8) (red curve) and for the sub-critical PLBRM Eq.(9) (blue curve) of unitary symmetry class computed analytically from Eqs.(11-14). For the anti-truncated critical RMT the non-monotonous behavior of log-log slope is similar to the one in Fig.15.

arguments similar to Eqs.(39,40) predict only one relevant energy scale $\omega_1 = b/\xi^{\alpha}$ such that for $\omega < \omega_1$ the correlation function $C(\omega)$ is constant and for $\omega > \omega_1$ (but $\omega < E_0 \sim b^{\alpha}$) it is a pure power law $C(\omega) \propto \omega^{-\frac{1}{\alpha}}$. Thus the sub-critical PLBRM is free from the drawback related with the unphysical second energy scale. For comparison we plotted the analytical results for the anti-truncated critical RMT and for the sub-critical PLBRM in Fig.16.





FIG. 17: Eigenfunction correlation in the 3D Anderson model: extended states. The disorder strength is W = 2 (green), W = 5 (red), W = 10 (blue). The system size is L = 8 (diamonds) L = 16 (circles) and L = 20 (squares). The correlation length is estimated from the inverse participation ratio as follows $\xi = (P_2 N/A_m)^{1/(d-d_2)}$ ($A_m = 0.5, d_2 = 1.3$) and is equal to: $\xi = 5.8, 3.2, 2.8$ at W = 10, 5, 2, respectively. In the insert we compare results for W = 5, L = 20 for the periodic (red filled squares) and the hard-wall (red open squares) boundary conditions. For hard-wall boundary conditions the correlation function looks "more critical", as the critical point $W_c = 15.2$ in this case is closer to W = 5.

It is seen that the overall shape of the blue curve for sub-critical PLBRM is much closer to the results of 3D Anderson model of Fig.17.

Note however, that the power-law emerging in the analytical results for the sub-critical PLBRM has an exponent $1/\alpha$ which is *larger* than the critical exponent. Computer simulations (see Fig.18a) on the sub-critical PLBRM with very small *b* confirm this analytical result as $N \to \infty$ extrapolation and show that the slope increases with increasing the system size N. However, the slope of the corresponding curves for the 3D Anderson model of Fig.17 is almost independent of the system size and is equal or *smaller* than the critical slope.

The reason for the discrepancy is that the analytical result for the slope $\mu = 1/\alpha$ corresponds to the limit $b \to 0$. At a finite b the slope decreases with increasing b and at a sufficiently large b may become smaller than the critical one. It is reasonable to assume that at small $1-\alpha$ and b this happens at $b \sim (1-\alpha)$. The relevance of the parameter $b/(1-\alpha)$ is also seen from the expression

FIG. 18: Eigenfunction correlations in the sub-critical PLBRM of the orthogonal symmetry class. Left panel (a): the small-b limit b = 0.001, $\alpha = 0.8$ at N = 1000 (squares) and N = 200 (diamonds). The critical correlations for b = 0.001, $\alpha = 1$ and N = 1000 are shown by stars. The solid line corresponds to the power-law ω^{-1} . The slope of the sub-critical curve is larger than 1 (correlations are short-range in the energy space). This case is relevant for the metallic phase of the Anderson model in very high dimensions. Right panel (b): the case b = 0.4, $\alpha = 0.95$ at N = 1000 (squares) and N = 200 (diamonds) is relevant for the Anderson model in d = 3 ("multifractal" metal). The slope is less than the critical (which in turn is less than 1) and is almost size-independent. Correlations are long-range in the energy space.

for the correlation length ξ

$$\xi \sim \exp\left[\frac{a_{\alpha}}{1-\alpha}\right], \quad a_{\alpha} = \ln\left(\frac{1-\alpha}{b^{\alpha}}\right) + \text{const.}$$
 (42)

which was found (up to a constant of order one) analytically from Eq.(16). This expression is apparently meaningless for $b^{\alpha} \gg (1 - \alpha)$ where c_{α} may become negative.

Numerical simulations on the sub-critical PLBRM with $1 - \alpha < b$ (e.g. for $\alpha = 0.95$ and b = 0.4 relevant for the 3D Anderson model) show (see Fig.18b) that the log-log slope of $C(\omega)$ is somewhat smaller than the critical one and is almost independent of the matrix size N. Thus the sub-critical PLBRM shows exactly the same character of eigenfunction correlations as in the 3D Anderson metal (see Fig.17).

Two parameters of the sub-critical PLBRM allow to simulate the effect of the finite correlation length (choice of $\alpha < 1$) and the dimensionality of space (choice of b). Note in this connection that for the disorder strength W significantly smaller than the critical value W_c , not only α but also b is W-dependent. The point is that in the 3D Anderson model the variance of the on-site energies fluctuations is proportional to W^2 , while the off-diagonal hopping integral is equal to 1. This implies that the ratio of a typical off-diagonal to a typical diagonal elements controlled in Eq.(9) by the parameter b should scale like 1/W. As the log-log slope of $C(\omega)$ decreases with increasing b, moving away from the Anderson transition into the metallic phase $W < W_c$ has an effect of decreasing the slope. On the insulator side of the transition the situation is opposite and one should expect an increase of the slope (for $\delta_{\xi} < \omega < E_0$) with increasing W. Fig.9 shows that it is apparently the case.

Another relevant note is that for the Anderson model in higher dimensions the correlation dimension d_2 decreases. This can be modeled by a decreasing parameter b. Then the analogy with the sub-critical PLBRM suggests that for sufficiently high dimensions $d > d_c$ the behavior in the d-dimensional Anderson model should become similar to the one in Fig.18a. Namely, the exponent μ in Eq.(7) may become larger than 1. This changes qualitatively the eigenfunction correlations, as they become effectively short-range in the energy space. In particular, the return probability⁹ which is proportional to the Fourier transform of $C(\omega)$ behaves in the time interval $\hbar/E_0 \ll t \ll \hbar/\delta_{\xi}$ as $P(t) \propto t^{-(1-\mu)}$ for $\mu < 1$ and is a constant for $\mu > 1$.

We believe that this qualitative change in the eigenfunction statistics (if confirmed for a *d*-dimensional Anderson model with $d > d_c$) should lead to dramatic physical consequences marking a transition to a new metallic state.

IX. CONCLUSION

In conclusion we list the main results obtained above. The most important of them is the persistence – beyond the point of localization transition– of the critical powerlaw in the dependence of the eigenfunction correlation function $C(\omega)$ on the energy separation ω and the related enhancement of $C(\omega)$ at $\delta_{\xi} \ll \omega \ll E_0$, where δ_{ξ} is the mean level spacing in the localization/correlation volume and E_0 is the upper energy cut-off of multifractality. This enhancement leads to an enhancement of matrix elements of local electron interaction which may result in, e.g. an enhancement of the superconducting transition temperature in the vicinity of the Anderson localization transition¹⁸. Another important observation is that the enhancement of correlations at $\omega < E_0$ is always accompanied by the depression at $\omega > E_0$, both phenomena being the consequences of the stratification of the coordinate space into mutually avoiding supports of the fractal structure with well overlapping eigenfunctions living on each of them. An independent – but also important- phenomenon is the logarithmic enhancement of $C(\omega)$ in the 2D and 3D Anderson insulator at $\omega < \delta_{\xi}$ (and the absence of such enhancement in the quasi-1D disordered wire). It is a result of a competition of two simultaneous phenomena: the repulsion of centers of localization and the resonance enhancement of the eigenfunction overlap by tails. Both phenomena are studied quantitatively within the Truncated Critical Random Matrix model which is suggested as a universal tool to describe the localized eigenfunctions with a multifractal texture. We also show that the sub-critical Power-Law Banded Random Matrix Ensemble suggested in Ref.¹⁴ describes the multifractal metal reasonably well. From the analytical solution for this RMT we conclude that a critical dimensionality d_c may exist above which the d-dimensional Anderson model has an unusual metal phase characterized by an effectively short-range correlation function $C(\omega) \propto \omega^{-\mu}$ with $\mu > 1$.

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